

BKKT 106, BKKT 106B, BKKH 106



Thyristor / Diode Modules

BKKT 106

BKKT 106B

BKKH 106

Features

- Heat transfer through aluminium oxide ceramic isolated metal baseplate
- Hard soldered joints for high reliability
- UL recognized, file no. E 63 532

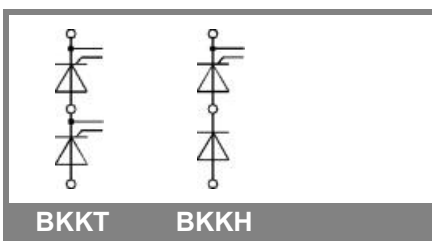
Typical Applications*

- DC motor control (e. g. for machine tools)
- AC motor soft starters
- Temperature control (e. g. for ovens, chemical processes)
- Professional light dimming (studios, theaters)

1) See the assembly instructions

V_{RSM} V	V_{RRM}, V_{DRM} V	$I_{TRMS} = 180$ A (maximum value for continuous operation) $I_{TAV} = 106$ A (sin. 180; $T_c = 85$ °C)		
900	800	BKKT 106/08E	BKKT 106B08E	BKKH 106/08E
1300	1200	BKKT 106/12E	BKKT 106B12E	BKKH 106/12E
1500	1400	BKKT 106/14E	BKKT 106B14E	BKKH 106/14E
1700	1600	BKKT 106/16E	BKKT 106B16E	BKKH 106/16E
1900	1800	BKKT 106/18E	BKKT 106B18E	BKKH 106/18E

Symbol	Conditions	Values	Units
I_{TAV}	sin. 180; $T_c = 85$ (100) °C;	106 (78)	A
I_D	P3/180F; $T_a = 35$ °C; B2 / B6	145 / 180	A
	P16/200F; $T_a = 35$ °C; B2 / B6	190 / 260	A
I_{RMS}	P3/180F; $T_a = 35$ °C; W1 / W3	200 / 3 * 140	A
I_{TSM}	$T_{vj} = 25$ °C; 10 ms	2250	A
	$T_{vj} = 130$ °C; 10 ms	1900	A
i^2t	$T_{vj} = 25$ °C; 8,3 ... 10 ms	25000	A ² s
	$T_{vj} = 130$ °C; 8,3 ... 10 ms	18000	A ² s
V_T	$T_{vj} = 25$ °C; $I_T = 300$ A	max. 1,65	V
$V_{T(TO)}$	$T_{vj} = 130$ °C	max. 0,9	V
r_T	$T_{vj} = 130$ °C	max. 2	mΩ
$I_{DD}; I_{RD}$	$T_{vj} = 130$ °C; $V_{RD} = V_{RRM}; V_{DD} = V_{DRM}$	max. 20	mA
t_{gd}	$T_{vj} = 25$ °C; $I_G = 1$ A; $di_G/dt = 1$ A/μs	1	μs
t_{gr}	$V_D = 0,67 * V_{DRM}$	2	μs
$(di/dt)_{cr}$	$T_{vj} = 130$ °C	max. 150	A/μs
$(dv/dt)_{cr}$	$T_{vj} = 130$ °C	max. 1000	V/μs
t_q	$T_{vj} = 130$ °C	100	μs
I_H	$T_{vj} = 25$ °C; typ. / max.	150 / 250	mA
I_L	$T_{vj} = 25$ °C; $R_G = 33$ Ω; typ. / max.	300 / 600	mA
V_{GT}	$T_{vj} = 25$ °C; d.c.	min. 3	V
I_{GT}	$T_{vj} = 25$ °C; d.c.	min. 150	mA
V_{GD}	$T_{vj} = 130$ °C; d.c.	max. 0,25	V
I_{GD}	$T_{vj} = 130$ °C; d.c.	max. 6	mA
$R_{th(j-c)}$	cont.; per thyristor / per module	0,28 / 0,14	K/W
	sin. 180; per thyristor / per module	0,3 / 0,15	K/W
	rec. 120; per thyristor / per module	0,32 / 0,16	K/W
$R_{th(c-s)}$	per thyristor / per module	0,2 / 0,1	K/W
T_{vj}		- 40 ... + 130	°C
T_{stg}		- 40 ... + 125	°C
V_{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 / 3000	V~
M_s	to heatsink	5 ± 15 % ¹⁾	Nm
M_t	to terminal	3 ± 15 %	Nm
a		5 * 9,81	m/s ²
m	approx.	95	g
Case	BKKT	A 46	
	BKKT ...B	A 48	
	BKKH	A 47	



BKKT

BKKH

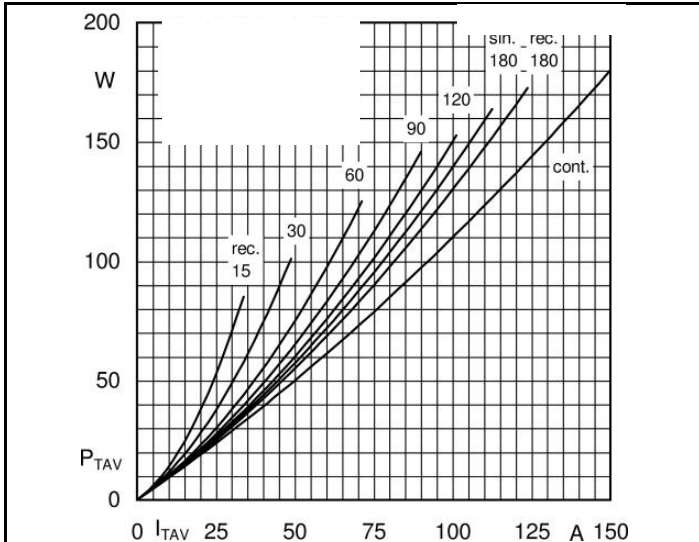


Fig. 1L Power dissipation per thyristor vs. on-state current

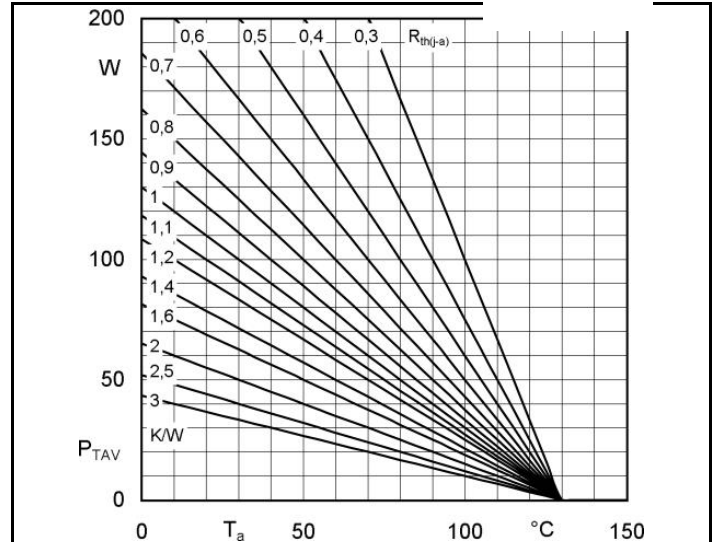


Fig. 1R Power dissipation per thyristor vs. ambient temp.

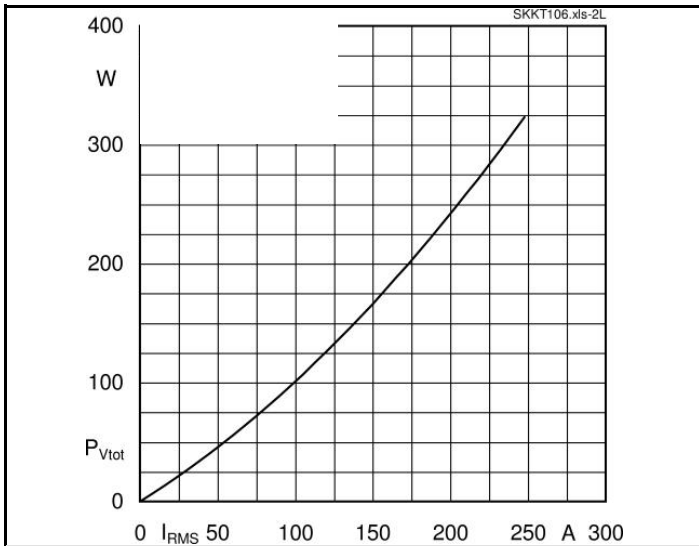


Fig. 2L Power dissipation per module vs. rms current

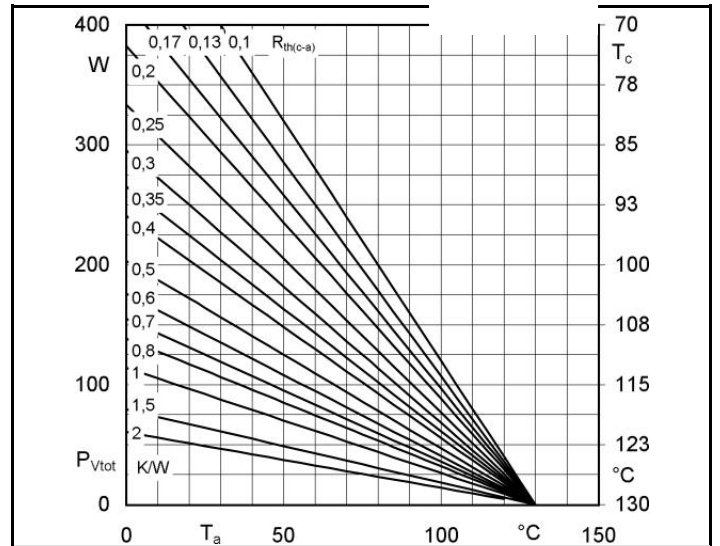


Fig. 2R Power dissipation per module vs. case temp.

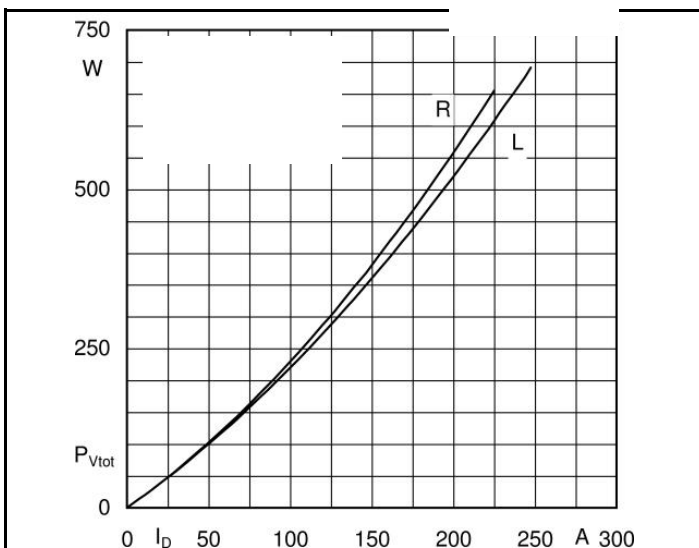


Fig. 3L Power dissipation of two modules vs. direct current

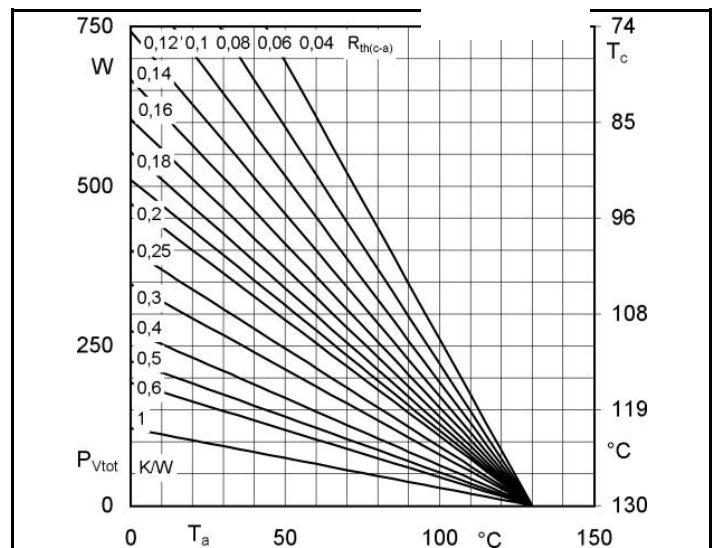
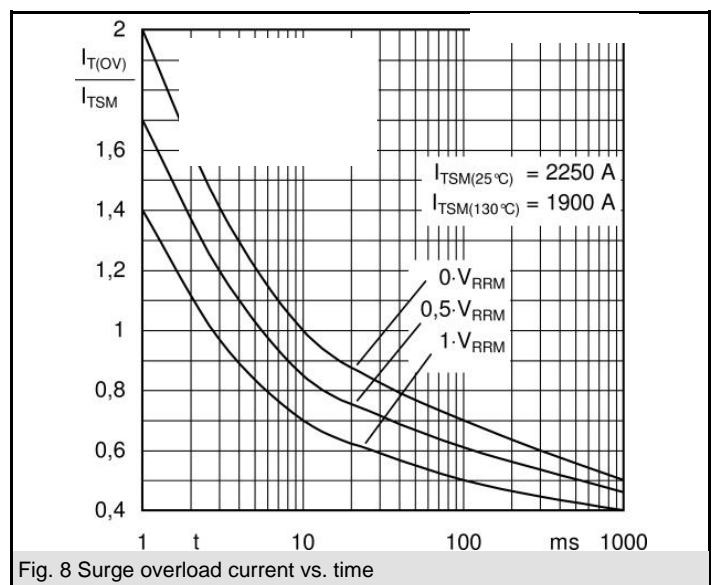
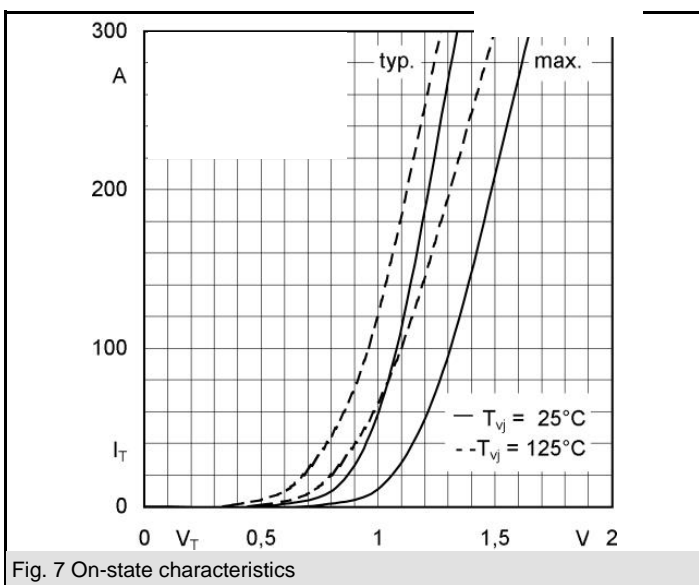
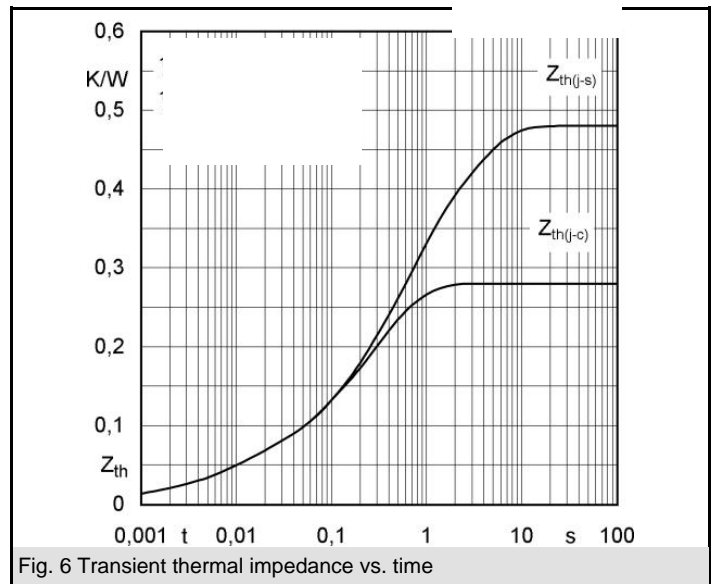
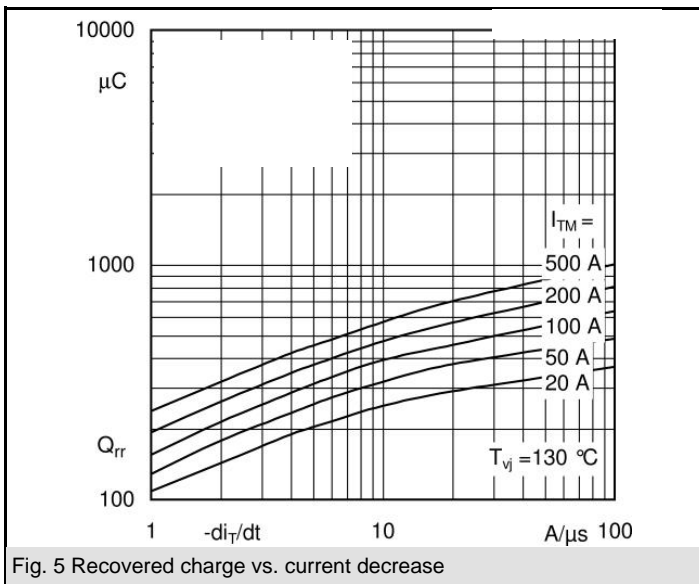
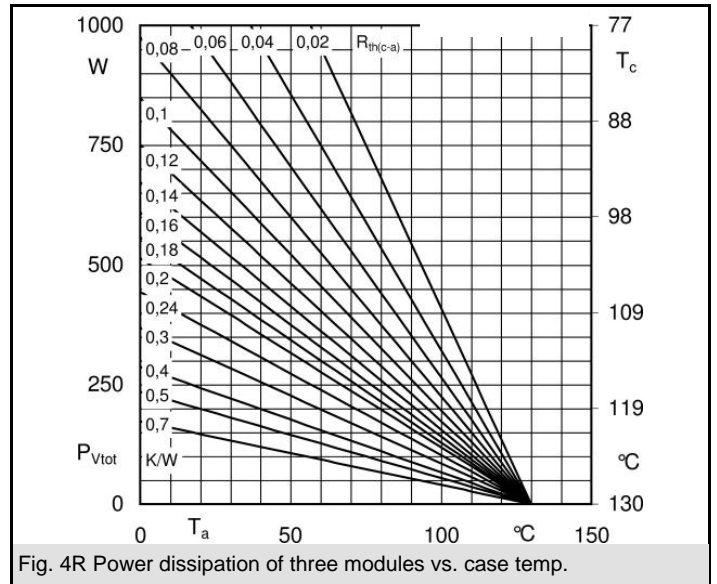
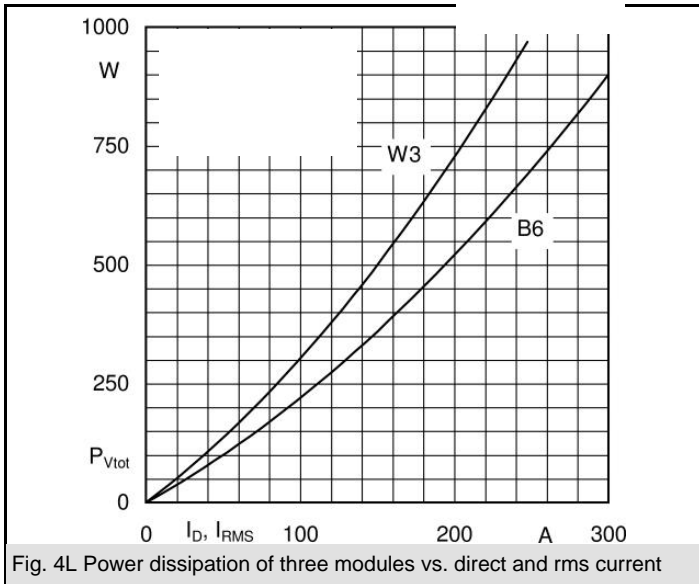


Fig. 3R Power dissipation of two modules vs. case temp.

BKKT 106, SKKT 106B, BKKH 106



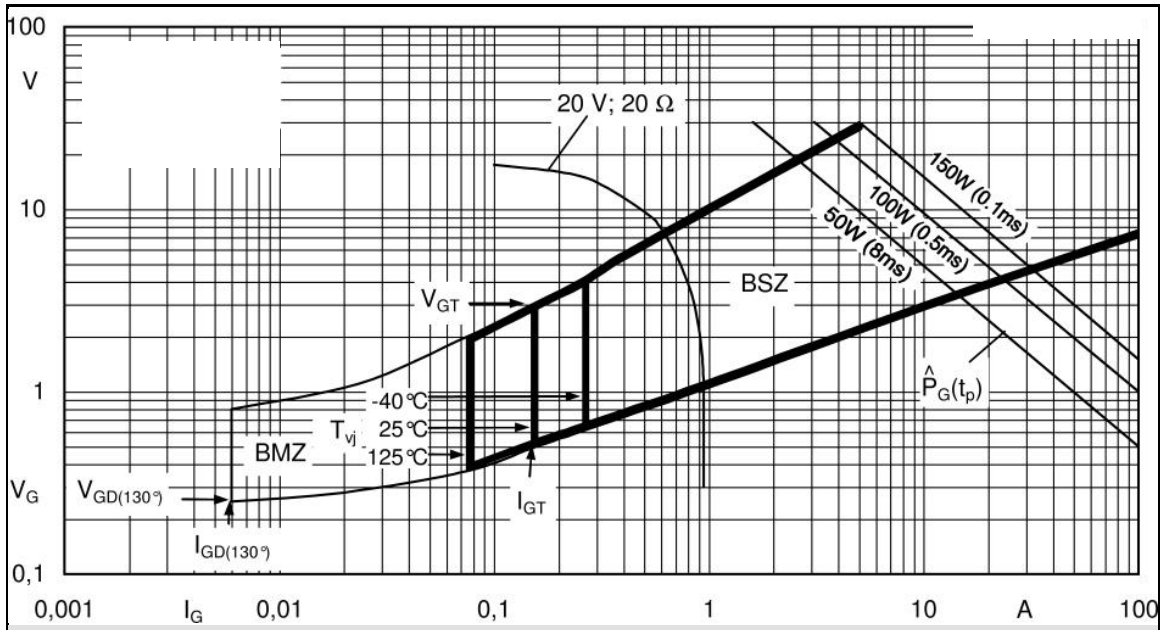
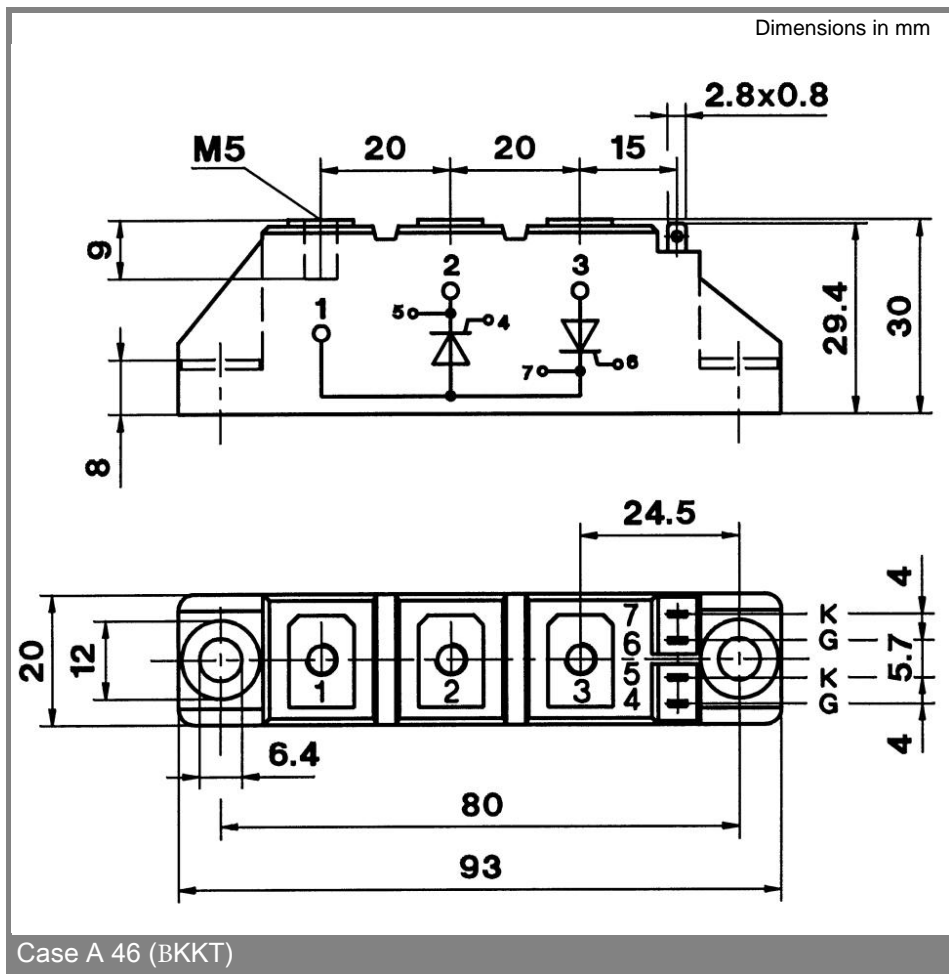
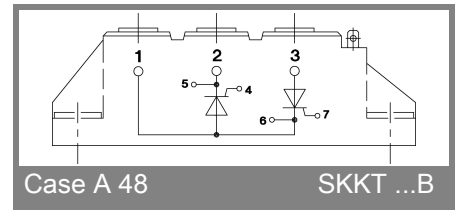


Fig. 9 Gate trigger characteristics

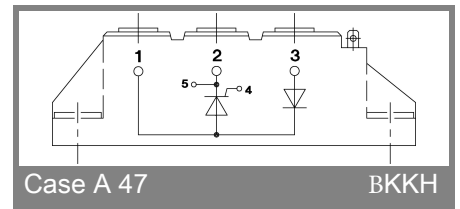


Case A 46 (BKKT)



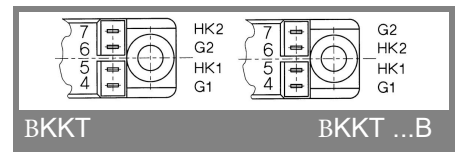
Case A 48

SKKT ...B



Case A 47

BKKH



BKKT

BKKT ...B

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of BILTEC products in life support appliances and systems is subject to prior specification and written approval by BILTEC. We therefore strongly recommend prior consultation of our personal.